



P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)			
	0.039 at V _{GS} = - 4.5 V	- 4.7			
- 20	0.052 at V _{GS} = - 2.5 V	- 4.1			
	0.068 at V _{GS} = - 1.8 V	- 3.5			

FEATURES

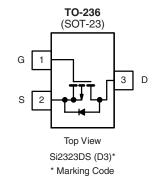
- Halogen-free According to IEC 61249-2-21 **Available**
- TrenchFET® Power MOSFET

COMPLIANT

HALOGEN FREE

APPLICATIONS

- Load Switch
- PA Switch



Ordering Information: Si2323DS-T1

Si2323DS-T1-E3 (Lead (Pb)-free)

Si2323DS-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	Γ _A = 25 °C, unle	ss otherwise r	noted		
Parameter	Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	- 20		V
Gate-Source Voltage		V _{GS}	± 8		V
Continuous Dusin Comment /T 150 00\8 h	T _A = 25 °C	- I _D	- 4.7	- 3.7	^
Continuous Drain Current (T _J = 150 °C) ^{a, b}	T _A = 70 °C		- 3.8	- 2.9	
Pulsed Drain Current		I _{DM}	- 20		Α
Continuous Source Current (Diode Conduction) ^{a, b}		I _S	- 1.0	- 0.6	
M. D. D ah	T _A = 25 °C	P _D 1.25 0.75 0.8 0.48	0.75	W	
Maximum Power Dissipation ^{a, b}	T _A = 70 °C		0.8	0.48	l vv
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55	to 150	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum landing to Audienta	t ≤ 5 s	R _{thJA}	75	100	
Maximum Junction-to-Ambient ^a	Steady State	' 'thJA	120	166	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	40	50	

- a. Surface Mounted on 1" x 1" FR4 board.
- b. Pulse width limited by maximum junction temperature.

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply.

Si2323DS

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SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
			Limits				
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_{D} = -250 \mu\text{A}$	- 20			V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \mu A$	- 0.40		- 1.0	v	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			± 100	nA	
Zana Oata Vallana Busin Oamani	lana	V _{DS} = - 16 V, V _{GS} = 0 V			- 1		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = - 16 V, V_{GS} = 0 V, T_J = 55 °C			- 10	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 20			Α	
		$V_{GS} = -4.5 \text{ V}, I_D = -4.7 \text{ A}$		0.031	0.039	Ω	
Drain-Source On-Resistance ^a	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 4.1 A		0.041	0.052		
		V _{GS} = - 1.8 V, I _D = - 2.0 A		0.054	0.068		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -5 \text{ V}, I_D = -4.7 \text{ A}$		16		S	
Diode Forward Voltage	V_{SD}	I _S = - 1.0 A, V _{GS} = 0 V		- 0.7	- 1.2	V	
Dynamic ^b							
Total Gate Charge	Qg	V 40VV 45V		12.5	19		
Gate-Source Charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}$ $I_{D} \cong -4.7 \text{ A}$		1.7		nC	
Gate-Drain Charge	Q_{gd}	D= 4.7 A		3.3		1	
Input Capacitance	C _{iss}			1020			
Output Capacitance	C _{oss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		191		pF	
Reverse Transfer Capacitance	C _{rss}			140			
Switching ^c			•	•			
Turn-On Time	t _{d(on)}	V 40V B 40 5		25	40		
	t _r	V_{DD} = - 10 V, R_L = 10 Ω $I_D \cong$ - 1.0 A, V_{GEN} = - 4.5 V		43	65		
Turn-Off Time	t _{d(off)}	$I_D = -1.0 \text{ A}, V_{GEN} = -4.5 \text{ V}$ $R_G = 6 \Omega$		71	110	ns	
	t _f	· ·G = 5 22		48	75		

Notes:

- a. Pulse test: PW \leq 300 μ s, duty cycle \leq 2 %.
- b. For DESIGN AID ONLY, not subject to production testing.
- c. Switching time is essentially independent of operating temperature.

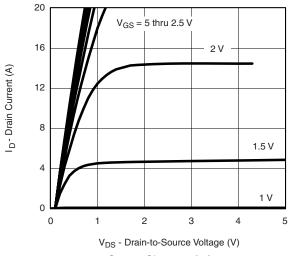
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



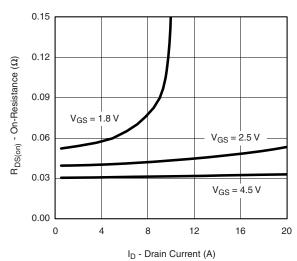




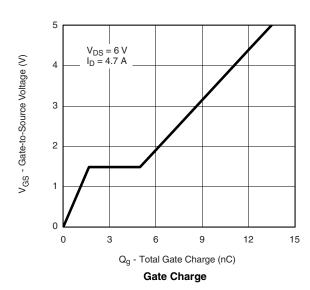
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



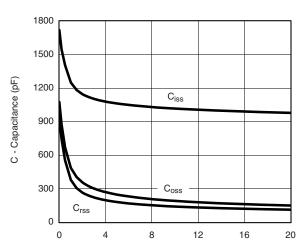
Output Characteristics



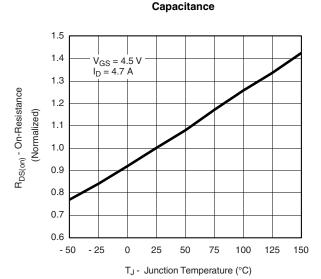
On-Resistance vs. Drain Current



V_{GS} - Gate-to-Source Voltage (V) **Transfer Characteristics**



 V_{DS} - Drain-to-Source Voltage (V)

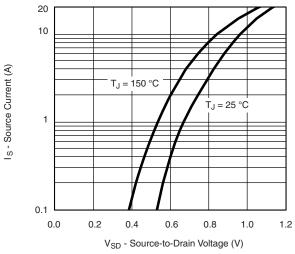


On-Resistance vs. Junction Temperature

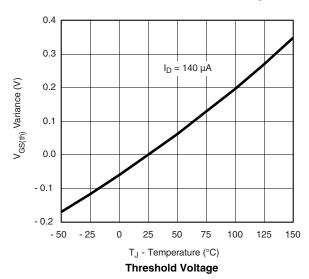
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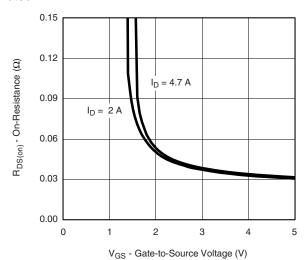
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

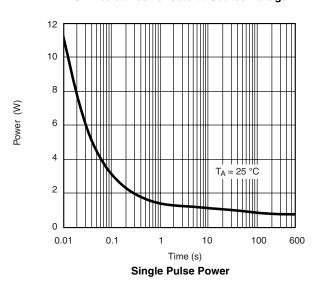


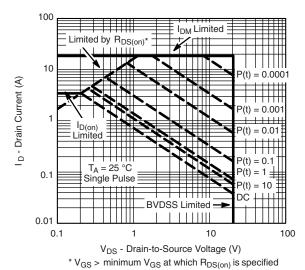
Source-Drain Diode Forward Voltage





On-Resistance vs. Gate-to-Source Voltage

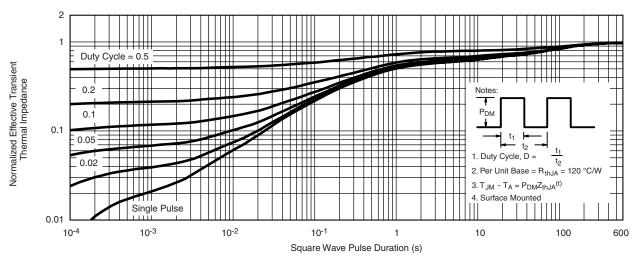




Safe Operating Area



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

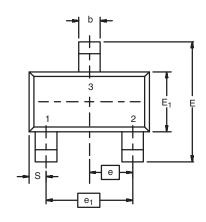


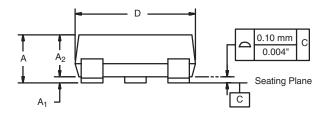
Normalized Thermal Transient Impedance, Junction-to-Ambient

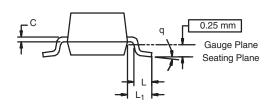
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SOT-23 (TO-236): 3-LEAD







Dim	MILLI	METERS	INCHES			
	Min	Max	Min	Max		
Α	0.89	1.12	0.035	0.044		
A ₁	0.01	0.10	0.0004	0.004		
A ₂	0.88	1.02	0.0346	0.040		
b	0.35	0.50	0.014	0.020		
С	0.085	0.18	0.003	0.007		
D	2.80	3.04	0.110	0.120		
E	2.10	2.64	0.083	0.104		
E ₁	1.20	1.40	0.047	0.055		
е	0.95 BSC		0.0374 Ref			
e ₁	1.90 BSC		0.074	0.0748 Ref		
L	0.40	0.60	0.016	0.024		
L ₁	0.64 Ref		0.025 Ref			
S	0.50 Ref		0.020 Ref			
q	3°	8°	3°	8°		
FCN: S-03946-Rev K 09-	lul-01	•				

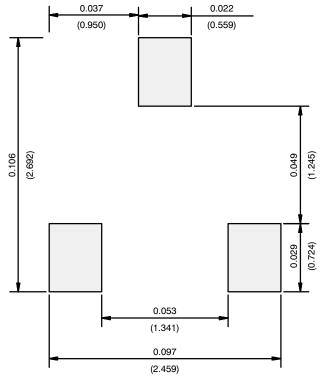
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RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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